ARPES-Lab

scientaomicron

The expert solution for Angle Resolved Photoemission Spectroscopy



ARPES-Lab What is state of the art in ARPES?

Angular resolved photoemission spectroscopy (ARPES) has emerged as the most powerful technique to understand the electronic structure of materials and what can influence their physics and chemistry.

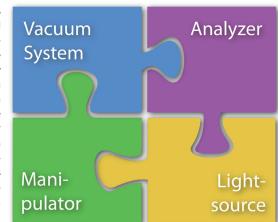
Revealing the band-structure of the valence band and the Fermi-level is fundamental to understanding electron transport, band-gap phenomena and spin-related effects. The progress of new technologies and the development of emergent materials rely more than ever on the ARPES technique to provide a precise understanding of the inherent abilities of complex material systems. This powerful tool is now being extended to time-resolved ARPES experiments yielding direct dynamical information during the evolution of electronic band structure. Scienta Omicron, the provider of the world leading electron spectrometers to specialist in the field, also offers complete turn-key automated ARPES measurement systems with guaranteed performance and expert local support as one of our "Materials Innovation Platforms".

ARPES-Lab advantages:

- Comprehensive solution from one supplier
- DA30-L deflector technology for precise
 ARPES results
- High photon density VUV sources with small beam spots
- He I and He II monochromators for minimal photon bandwidth
- Ease of use by interplay with system and measurment software
- User-friendly adjustment of light-source and manipulator
- Expert support for configuration and design
- World-wide local Sales and Service-Support

The key to ultimate ARPES performance is the optimal integration of high class components to a comprehensive system. The ultimate energy and angular resolution of a measurement depends on the analyzer as well as on the light source, the manipulator cooling and the manipulation precision. Advanced measuements of sensitive samples need a powerful vacuum system and an effective shielding.

The Scienta Omicron ARPES-Lab performs band structure mapping measurements faster, more precisely, yielding data sets with fewer variables for simplified data analysis than any other system available. Magnetically shielded chambers and cryogenic sample manipulators that are the standard for many advanced synchrotron endstations are the building blocks to the Scienta Omicron ARPES-Lab.

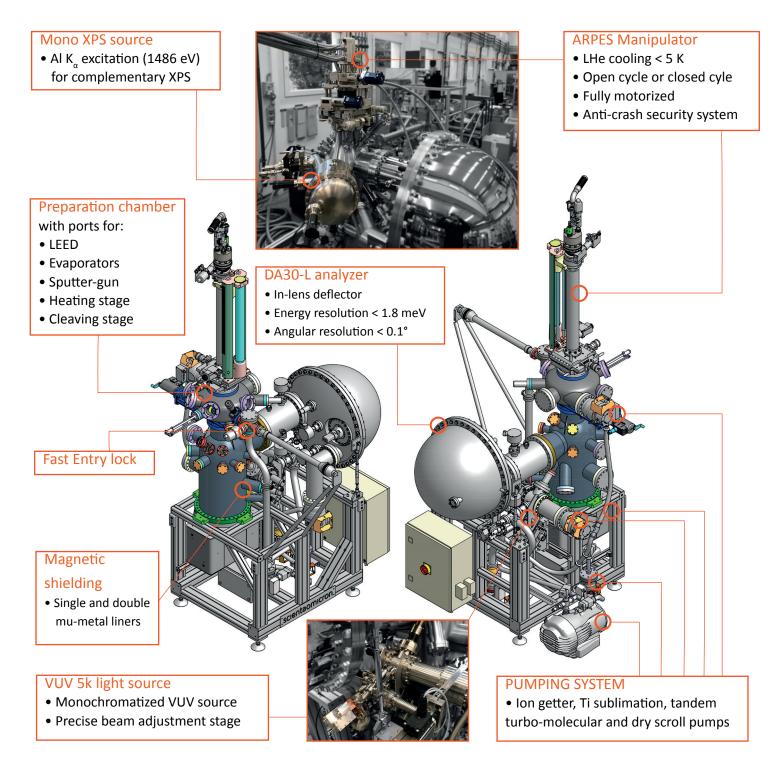


Intelligently integrated with superior automatization and software control from data acquisition reaching through vacuum control, the ARPES-Lab brings the powerful ARPES technique into an accesable and reliable measurement tool. A pumping system optimized to lowest working pressures even when operating with He-discharge lamps extends sample lifetime and integrity.

Best technology concept

The ARPES-Lab is designed to maximize the advantages gained from the revolutionary DA30-L hemispherical high-resolution analyzer with its patented in-lens deflector. The analyzer measures the full 3D surface cone of a band-structure without sample tilt by deflecting the electron trajectories perpendicular to the analyzer entrance slit, which allows for:

- Improved k_y accuracy in shorter measurement times
- Maintains near constant matrix elements by keeping sample angle fixed
- Ensures reliable measurement position on a fixed sample point necessary for exploring dichroic effects in ARPES and measuring very small samples and/or multi-domain samples



For wide range Brillouin zone scans the motorized sample manipulator is integrated into the measurement (SES) and system software (MISTRAL). The software driven adjustment of the manipulator allows for:

Precise sample movement during scans

 Automatic movement of the sample between different measurement positions (ARPES, LEED, etc.)

Security interlocks for manipulator movement

All manipulators (4, 5 or 6 axis) reach very low temperatures (< 10 K) to allow for high energy resolution.

Experts in magnetic shielding design have perfected the chamber to achieve the highest performance from the combination of analyzer and excitation sources.

The ARPES-Lab can support multiple light sources covering a broad energy range to enable investigation of all class of materials. The renown VUV5k high intensity monochromatic light source can be paired with new laser sources providing selectable energies and polarization exhibiting extremely narrow line width and/or ultra fast pulse width for time resolved ARPES. The ARPES-Lab can additionally support a monochromatic x-ray source for core level chemical state analysis.

Designs incorporating the latest techniques are available; additionally Scienta Omicron can custom tailor the system to enable your unique ideas.

Scienta Omicron Multi-technique from one company

Powerful Materials Innovation Platforms can be created by integration with Scienta Omicron thin film growth systems such as MBE plus scanning probe techniques such as STM-AFM to our Low Temperature Nanoprobe for cryogenic transport measurements. Sample preparation and spin filter options are available for extending the scientific possibilities.

World-wide service and support centers

A wide range of options allow for tailoring the system to the specific needs < 300 µm Yes Yes 1.0 meV 0.5-12 eV (angular mode) < 100 nT

Options

Light sources

Energy range

capabilities

Manipulators

stabilization

Vacuum Chamber

ports

of individual reasearch. For example:

HIS 14 HD for small beam spots Laser

improved magnetic shielding double

chamber design with preparation

4-, 5-, and 6- axes, upgradeable

Closed cycle He cooling

Counter heating for temp

Base temperatures

Monochromatized x-ray sources

DA30-L 8000 analyzer

Energy resolution, analyzer*

ves

ves yes 3.5 K-10 K, depends on model for all models

*Component specification, Total performance depends on component configuration. Please contact us for details.

1487 eV (AI), 1254 eV (Mg)

x, y, z, polar, azimuthal

Target Specification

3-1500 eV (angular mode)

1.8 meV

+- 15° full cone

< 1F-10 mBar

< 5E-10 mBar

> 1E12 ph/s/mm²

 0.1°

yes

ves

all

Yes

Yes

Yes

< 500 nT

< 600 µm

1 meV (He I)

< 6 K .. 400 K

** These set-up is an example configuration. Please contact us for your personal configuration.

Technical Data

Stainless steel chamber with mu-metal liner, DA30-L analyzer, VUV 5k VUV

source, XPS source, LHe 5-ax manipulator open cycle **

ARPES-Lab UPS/XPS

Energy resolution, analyzer*

Angular resolution, analyzer*

Magnetic shielding, chamber

Pressure during operation

VUV photon flux density

VUV beam spot size

VUV energy-resolution

XPS excitation energy

Super stable electronics

MISTRAL System Control

SES Analysis Software

Measurment axis motorization

Manipulator temperature range

Manipulator axis

Base pressure, analysis chamber

Deflector mode for full cone detection

Fast He pumping (tandem turbo pump)

Angular resolved range

Property

Energy range